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DATA SHEET

PART NO. : PA-ITRLT8402

REV : A / 0

CUSTOMER'S APPROVAL : _____

DCC : _____

DRAWING NO. : DS-81P-22-0022

DATE : 2022-07-23

Page : 1

LD-R/E020

Descriptions

The PA-ITRLT8402 consist of an infrared emitting diode and an NPN silicon phototransistor, encased side-by-side on converging optical axis in a black thermoplastic housing . The phototransistor receives radiation from the IRED only .This is the normal situation.

But when an object is in between , phototransistor could not receives the radiation.

For additional component information , please refer to IR and PT

Features

Fast response time

High analytic

Cut-off visible wavelength $\lambda_p=940\text{nm}$

High sensitivity

Pb free

This product itself will remain within RoHS compliant version.

Applications

Mouse Copier

Switch Scanner

Floppy disk driver

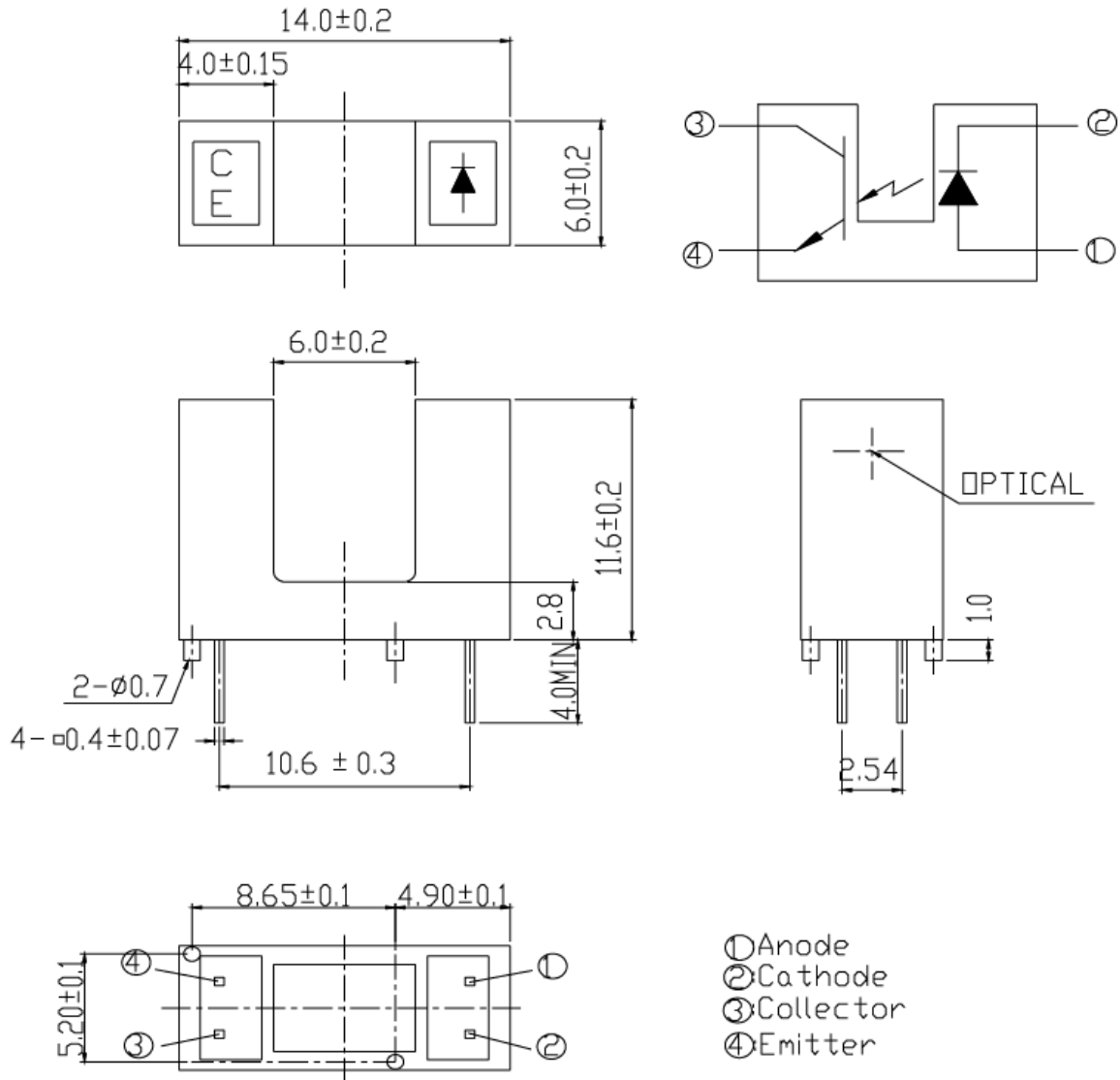
Non-contact Switching

For Direct Board

Device Selection Guide

Device No.	Chip Material	LENS COLOR
IR	GaAIAs	Water clear
PT	Silicon	Water clear

Package Dimension



Note:

1. All dimensions are in millimeters.
2. Tolerances unless dimensions ± 0.3 mm.
3. Lead spacing is measured where the lead emerge from the package



INFRARED REMOTE CONTROL RECEIVER MODULE

PA-ITRLT8402

REV:A / 0

Absolute Maximum Ratings

Parameter		Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
	Reverse Voltage	V _R	5	V
	Forward Current	I _F	50	mA
	Peak Forward Current (*1) Pulse width ≤100μs, Duty cycle=1%	I _{FP}	1	A
Output	Collector Power Dissipation	P _C	75	mW
	Collector Current	I _C	20	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	V
Operating Temperature		T _{opr}	-25~+85	°C
Storage Temperature		T _{stg}	-40~+100	°C
Lead Soldering Temperature (*2) (1/16 inch form body for 5 seconds)		T _{sol}	260	°C

(* 1) $t_w=100 \mu\text{sec.}$, $T=10 \text{ msec.}$ (* 2) $t=5 \text{ Sec}$

Electro-Optical Characteristics

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input	Forward Voltage	V _{F1}	---	1.2	1.5	V	I _F =20mA
	Reverse Current	I _R	---	---	10	μA	V _R =5V
	Peak Wavelength	λ _P	---	940	---	nm	I _F =20mA
	View Angle	2θ _{1/2}	---	40	---	Deg	I _F =20mA
Output	Dark Current	I _{CEO}	---	---	100	nA	V _{CE} =20V, E _e =0mW/cm ²
	C-E Saturation Voltage	V _{CE(sat)}	---	---	0.4	V	I _C =2mA , E _e =1mW/cm ²
Transfer Characteristics	Collect Current	I _{C(ON)}	0.5	---	--	mA	V _{CE} =5V I _F =20mA
		I _{C(OFF)}	---	--	20	μA	
	Rise time	t _r	---	15	---	μsec	V _{CE} =5V I _C =1mA R _L =1KΩ
	Fall time	t _f	---	15	---	μsec	

Typical Electrical/Optical/Characteristics Curves for IR

Fig.1 Forward Current vs.

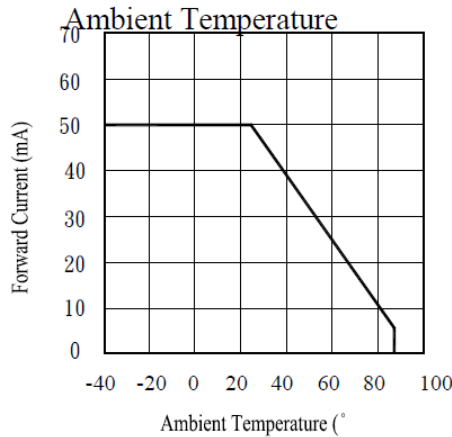


Fig.2 Spectral Distribution

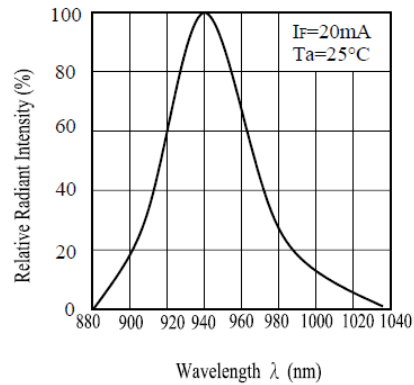


Fig.5 Relative Intensity vs.

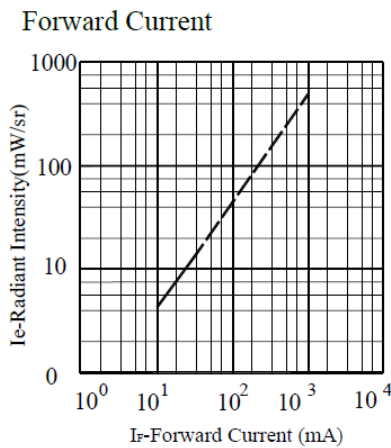


Fig.6 Relative Radiant Intensity vs.

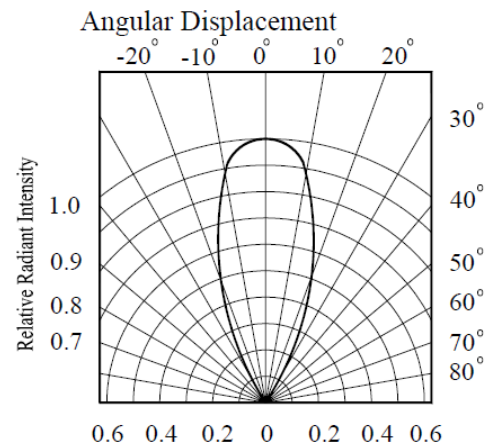


Fig.7 Relative Intensity vs.

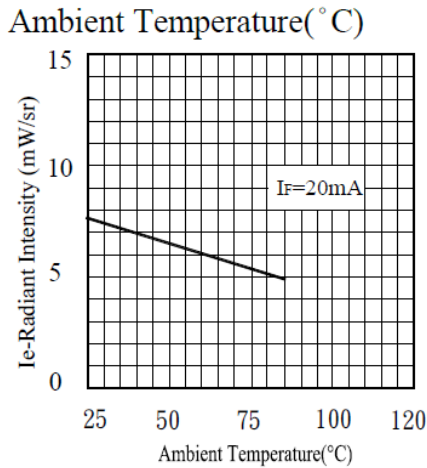
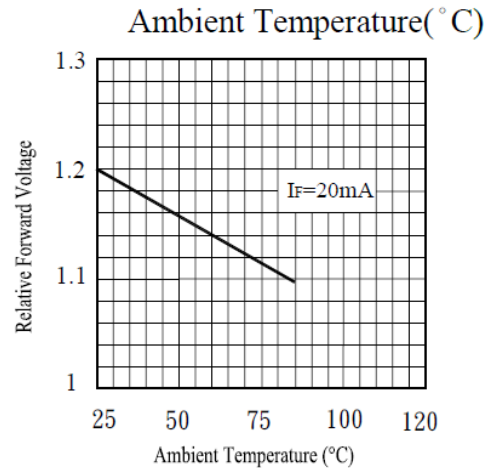


Fig.8 Forward Current vs.



Typical Electrical/Optical/Characteristics Curves for PT

Fig.1 Collector Power Dissipation vs. Ambient Temperature

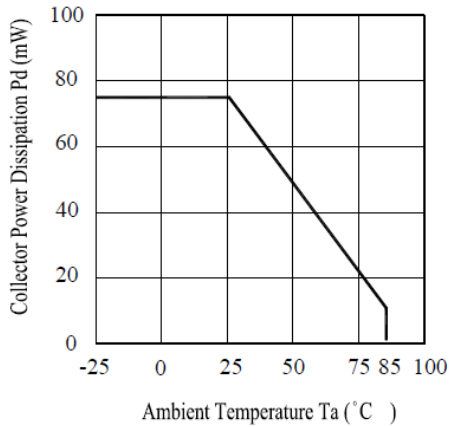


Fig.2 Spectral Sensitivity

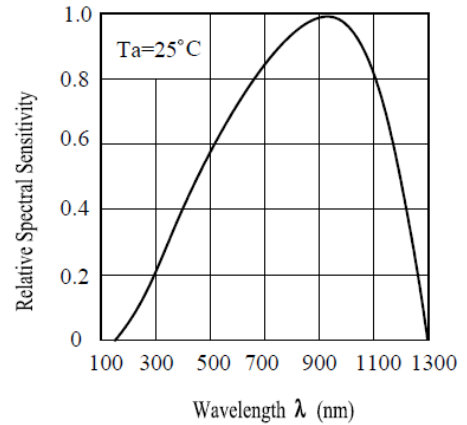


Fig.3 Relative Collector Current vs. Ambient Temperature

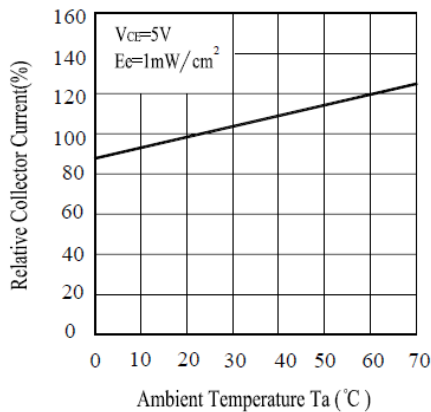


Fig.4 Collector Current vs. Irradiance

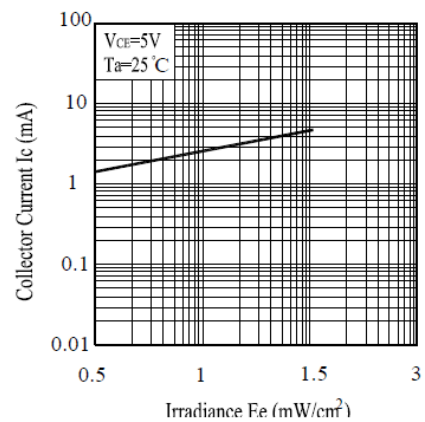


Fig.5 Collector Dark Current vs. Ambient Temperature

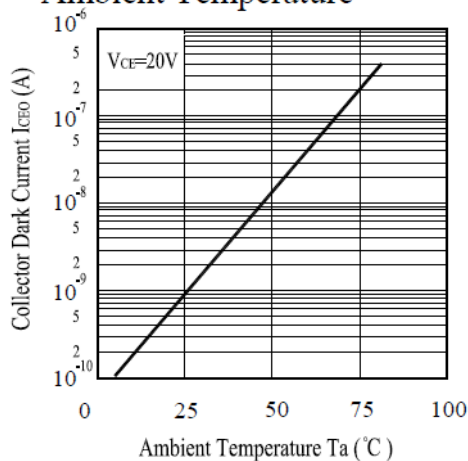
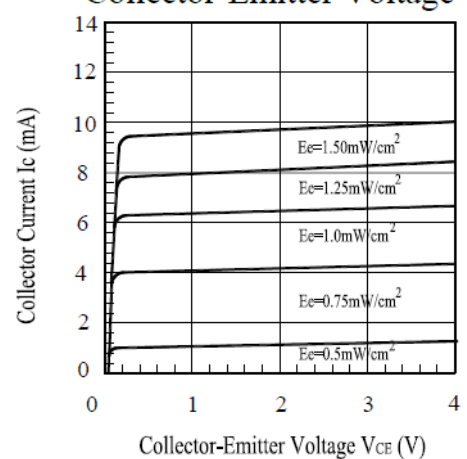


Fig.6 Collector Current vs. Collector-Emitter Voltage



● Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level: 90%

LTPD: 10%

NO.	Item	Test Condition	Test Hours/ Cycle	Sample Size	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP : 260°C ± 5 °C	10sec	22 PCs	More than 90% of lead to be covered by soldering	0/1
2	Temperature Cycle	H : +100°C 15 mins \updownarrow 5 min \updownarrow L : -40°C 15 min	300 cycle	22 PCs	$I_R \geq U \times 2$ $E_e \leq L \times 0.8$ $V_F \geq U \times 1.2$	0/1
3	Thermal Shock	H : +100°C 5 min \updownarrow 10 sec \updownarrow L : -10°C 5 min	300 cycle	22 PCs	U : Upper specification limit L : Lower specification limit	0/1
4	High Temperature Storage	TEMP. : +100°C	1000 hrs	22 PCs		0/1
5	Low Temperature Storage	TEMP. : -40°C	1000 hrs	22 PCs		0/1
6	DC Operating Life	$V_{CE} = 5V$ $I_F = 20mA$	1000 hrs	22 PCs		0/1
7	High Temperature / High Humidity	85°C / 85% R.H.	1000 hrs	22 PCs		0/1

Packing Quantity Specification

150 pcs/1bag, 4 bags/1box, 10 boxes/1carton



INFRARED REMOTE CONTROL RECEIVER MODULE

PA-ITRLT8402

REV:A / 0

Notes

1. Above specification may be changed without notice. WE will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instruction for using outlined in these specification sheets. Para light assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
3. These specification sheets include materials protected under copyright of corporation. Please don't reproduce or cause anyone to reproduce them without Para light's consent.